



1.2MHz, 0.4V/μs Over-The-Top Micropower Rail-to-Rail Input and Output Op Amps

FEATURES

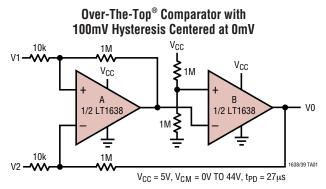
- Operates with Inputs Above V⁺
- Rail-to-Rail Input and Output
- Low Power: 230µA per Amplifier Max
- Gain Bandwidth Product: 1.2MHz
- Slew Rate: 0.4V/µs
- High Output Current: 25mA Min
- Specified on 3V, 5V and ±15V Supplies
- Reverse Battery Protection to 18V
- No Supply Sequencing Problems
- High Voltage Gain: 1500V/mV
- Single Supply Input Range: -0.4V to 44V
- High CMRR: 98dB
- No Phase Reversal
- Available in 14-Lead SO, 8-Lead MSOP and DFN Packages

APPLICATIONS

- Battery- or Solar-Powered Systems Portable Instrumentation Sensor Conditioning
- Supply Current Sensing
- Battery Monitoring
- Micropower Active Filters
- 4mA to 20mA Transmitters

T, LTC and LT are registered trademarks of Linear Technology Corporation. Over-The-Top is a registered trademark of Linear Technology Corporation. All other trademarks are the property of their respective owners.

TYPICAL APPLICATION



DESCRIPTION

The LT[®]1638 is a low power dual rail-to-rail input and output operational amplifier available in the standard 8-pin PDIP and SO packages as well as the 8-lead MSOP package. The LT1639 is a low power quad rail-to-rail input and output operational amplifier offered in the standard 14-pin PDIP and surface mount packages. For space limited applications the LT1638 is available in a 3mm x 3mm x 0.8mm dual fine pitch leadless package (DFN).

The LT1638/LT1639 op amps operate on all single and split supplies with a total voltage of 2.5V to 44V drawing only 170μ A of quiescent current per amplifier. These amplifiers are reverse battery protected and draw no current for reverse supply up to 18V.

The input range of the LT1638/LT1639 includes both supplies, and a unique feature of this device is its capability to operate over the top with either or both of its inputs above V⁺. The inputs handle 44V, both differential and common mode, independent of supply voltage. The input stage incorporates phase reversal protection to prevent false outputs from occurring when the inputs are below the negative supply. Protective resistors are included in the input leads so that current does not become excessive when the inputs are forced below the negative supply. The LT1638/LT1639 can drive loads up to 25mA and still maintain rail-to-rail capability. The op amps are unity-gain stable and drive all capacitive loads up to 1000pF when optional output compensation is used.

SV Dutput Voltage vs Input Voltage

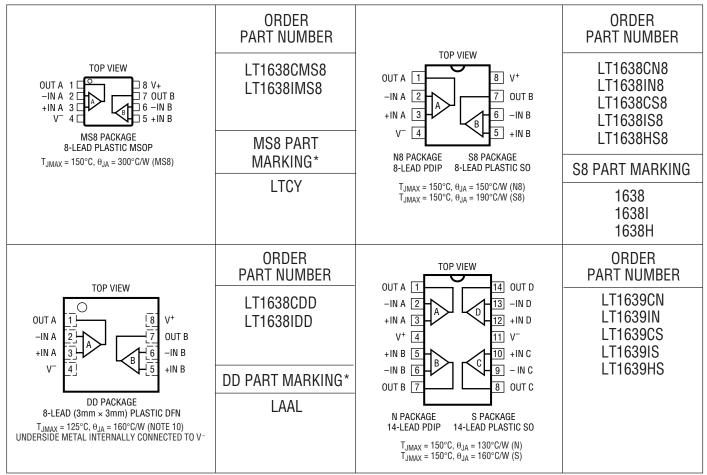
.

ABSOLUTE MAXIMUM RATINGS (Note 1)

Total Supply Voltage (V ⁺ to V ⁻)	44V
Input Differential Voltage	44V
Input Current	±25mA
Output Short-Circuit Duration (Note 2).	Continuous
Operating Temperature Range (Note 3)	
LT1638C/LT1639C	–40°C to 85°C
LT1638I/LT1639I	–40°C to 85°C
LT1638H/LT1639H	-40°C to 125°C

Specified Temperature Range (Note 4)
LT1638C/LT1639C –40°C to 85°C
LT1638I/LT1639I40°C to 85°C
LT1638H/LT1639H –40°C to 125°C
Junction Temperature 150°C
DD Package 125°C
Storage Temperature Range –65°C to 150°C
DD Package –65°C to 125°C
Lead Temperature (Soldering, 10 sec)

PACKAGE/ORDER INFORMATION



*The temperature grades are identified by a label on the shipping container. Consult LTC Marketing for parts specified with wider operating temperature ranges.



ELECTRICAL CHARACTERISTICS

The \bullet denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = 3V$, 0V; $V_S = 5V$, 0V; $V_{CM} = V_{OUT}$ = half supply, unless otherwise noted. (Note 4)

SYMBOL	PARAMETER	CONDITIONS		LT1638C/LT Min	1639C, LT1 Typ	638I/LT1639I MAX	UNITS
V _{OS}	Input Offset Voltage	LT1638 N, S Packages $0^{\circ}C \le T_A \le 70^{\circ}C$ $-40^{\circ}C \le T_A \le 85^{\circ}C$	•		200	600 850 950	μV μV μV
		LT1639 N, S Packages $0^{\circ}C \le T_A \le 70^{\circ}C$ $-40^{\circ}C \le T_A \le 85^{\circ}C$	•		300	700 950 1050	μV μV
		LT1638 MS8 Package $0^{\circ}C \le T_A \le 70^{\circ}C$ $-40^{\circ}C \le T_A \le 85^{\circ}C$	•		350	900 1150 1450	μV μV μV
		LT1638 DD Package $0^{\circ}C \le T_A \le 70^{\circ}C$ $-40^{\circ}C \le T_A \le 85^{\circ}C$	•		400	1100 1350 1450	μV μV μV
	Input Offset Voltage Drift (Note 9)	LT1638/LT1639 N, S Packages LT1638MS8, LT1638DD	•		2 2.5	6 7	μV/°C μV/°C
I _{OS}	Input Offset Current	V _{CM} = 44V (Note 5)	•		1	6 2.5	nA μA
I _B	Input Bias Current	V _{CM} = 44V (Note 5) V _S = 0V	•		20 8 0.1	50 30	nA µA nA
	Input Noise Voltage	0.1Hz to 10Hz			1		μν _{Ρ-Ρ}
e _n	Input Noise Voltage Density	f = 1kHz			20		nV/√Hz
i _n	Input Noise Current Density	f = 1kHz			0.3		pA/√Hz
R _{IN}	Input Resistance	Differential Common Mode, V _{CM} = 0V to 44V		1 1.4	2.5 5.5		ΜΩ ΜΩ
CIN	Input Capacitance				5		pF
	Input Voltage Range		•	0		44	V
CMRR	Common Mode Rejection Ratio	$V_{CM} = 0V$ to $V_{CC} - 1V$ $V_{CM} = 0V$ to 44V (Note 8)	•	88 80	98 88		dB dB
A _{VOL}	Large-Signal Voltage Gain	$V_{S} = 3V, V_{0} = 500mV \text{ to } 2.5V, R_{L} = 10k$ $0^{\circ}C \le T_{A} \le 70^{\circ}C$ $-40^{\circ}C \le T_{A} \le 85^{\circ}C$	•	200 133 100	1500		V/mV V/mV V/mV
		$V_{S} = 5V, V_{0} = 500mV \text{ to } 4.5V, R_{L} = 10k$ $0^{\circ}C \le T_{A} \le 70^{\circ}C$ $-40^{\circ}C \le T_{A} \le 85^{\circ}C$	•	400 250 200	1500		V/mV V/mV V/mV
V _{OL}	Output Voltage Swing Low	$V_{S} = 3V$, No Load $V_{S} = 3V$, I _{SINK} = 5mA	•		3 250	8 450	mV mV
		$V_{S} = 5V$, No Load $V_{S} = 5V$, I _{SINK} = 10mA	•		3 500	8 700	mV mV
V _{OH}	Output Voltage Swing High	$V_{S} = 3V$, No Load $V_{S} = 3V$, I _{SOURCE} = 5mA	•	2.94 2.25	2.98 2.40		V V
		$V_S = 5V$, No Load $V_S = 5V$, I _{SOURCE} = 10mA	•	4.94 3.8	4.98 4.0		V V
I _{SC}	Short-Circuit Current (Note 2)	$V_{S} = 3V$, Short to GND $V_{S} = 3V$, Short to V_{CC}		10 15	15 25		mA mA
		$V_{S} = 5V$, Short to GND $V_{S} = 5V$, Short to V_{CC}		15 15	20 25		mA mA



ELECTRICAL CHARACTERISTICS

The \bullet denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = 3V$, 0V; $V_S = 5V$, 0V; $V_{CM} = V_{OUT} = half$ supply, unless otherwise noted. (Note 4)

		LT1638C/LT1	1639C, LT1	638I/LT1639I			
SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
PSRR	Power Supply Rejection Ratio	$V_{S} = 3V$ to 12.5V, $V_{CM} = V_{0} = 1V$	•	90	100		dB
	Reverse Supply Voltage	$I_{S} = -100 \mu A$ per Amplifier	•	18	27		V
	Minimum Operating Supply Voltage		•		2.4	2.7	V
I _S	Supply Current per Amplifier (Note 6)		•		170	230 275	μΑ μΑ
GBW	Gain Bandwidth Product (Note 5)	f = 5kHz 0°C ≤ T _A ≤ 70°C −40°C ≤ T _A ≤ 85°C	•	650 550 500	1075		kHz kHz kHz
SR	Slew Rate (Note 7)	$\begin{array}{l} A_V = -1, \ R_L = \infty \\ 0^\circ C \leq T_A \leq 70^\circ C \\ -40^\circ C \leq T_A \leq 85^\circ C \end{array}$	•	0.210 0.185 0.170	0.38		V/µs V/µs V/µs

The \bullet denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = \pm 15V$, $V_{CM} = 0V$, $V_{OUT} = 0V$, unless otherwise noted. (Note 4)

				LT1638C/LT	1639C, LT1	538I/LT1639I	1
SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{OS}	Input Offset Voltage	LT1638 N, S Packages			250	800	μV
		$0^{\circ}C \le T_{A} \le 70^{\circ}C$	•			1000	μV
		$-40^{\circ}C \le T_A \le 85^{\circ}C$	•			1100	μV
		LT1639 N, S Packages			350	900	μV
		$0^{\circ}C \le T_{A} \le 70^{\circ}C$	•			1100	μV
		$-40^{\circ}C \le T_A \le 85^{\circ}C$	•			1200	μV
		LT1638 MS8 Package			400	1050	μV
		$0^{\circ}C \le T_A \le 70^{\circ}C$	•			1250	μV
		$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le 85^{\circ}\text{C}$	•			1550	μV
		LT1638 DDPackage			450	1250	μV
		$0^{\circ}C \le T_A \le 70^{\circ}C$ -40^{\circ}C \le T_A \le 85^{\circ}C				1450 1550	μV μV
			•		0		
	Input Offset Voltage Drift (Note 9)	LT1638/LT1639 N, S Packages LT1638MS8, LT1638DD			2 2.5	6 7	μV/°C μV/°C
I _{OS}	Input Offset Current				1	6	nA
	Input Bias Current				20	50	nA
I _B					20	50	
	Input Noise Voltage	0.1Hz to 10Hz			1		μV _{P-P}
e _n	Input Noise Voltage Density	f = 1kHz			20		nV/√Hz
i _n	Input Noise Current Density	f = 1kHz			0.3		pA/√Hz
R _{IN}	Input Resistance	Differential		1	2.5		MΩ
		Common Mode, $V_{CM} = -15V$ to 14V			500		MΩ
CIN	Input Capacitance				4.5		pF
	Input Voltage Range		•	-15		29	V
CMRR	Common Mode Rejection Ratio	V _{CM} = -15V to 29V	•	80	88		dB
A _{VOL}	Large-Signal Voltage Gain	$V_0 = \pm 14V, R_L = 10k$		200	500		V/mV
		$0^{\circ}C \le T_{A} \le 70^{\circ}C$		125			V/mV
		$-40^{\circ}C \le T_A \le 85^{\circ}C$	•	100			V/mV
V ₀	Output Voltage Swing	No Load	•	±14.9	±14.95		V
		$I_{OUT} = \pm 10 \text{mA}$		±13.7	±14.0		V



ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the specified temperature range, otherwise specifications are at T_A = 25°C. V_S = ±15V, V_{CM} = 0V, V_{OUT} = 0V, unless otherwise noted. (Note 4)

		LT1638C/LT1639C, LT1638I/LT16					I	
SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS	
I _{SC}	Short-Circuit Current (Note 2)	Short to GND $0^{\circ}C \le T_A \le 70^{\circ}C$ $-40^{\circ}C \le T_A \le 85^{\circ}C$	•	25 20 15	40		mA mA mA	
PSRR	Power Supply Rejection Ratio	$V_{\rm S} = \pm 1.5 V \text{ to } \pm 22 V$	•	90	100		dB	
I _S	Supply Current per Amplifier		•		205	280 350	μΑ μΑ	
GBW	Gain Bandwidth Product	$f = 5kHz$ $0^{\circ}C \le T_{A} \le 70^{\circ}C$ $-40^{\circ}C \le T_{A} \le 85^{\circ}C$	•	750 650 600	1200		kHz kHz kHz	
SR	Slew Rate	$ \begin{array}{l} A_V = -1, \; R_L = \infty, V_0 = \pm 10V, \\ 0^\circ C \leq T_A \leq 70^\circ C \\ -40^\circ C \leq T_A \leq 85^\circ C \end{array} $	•	0.225 0.2 0.18	0.4		V/μS V/μS V/μS	

The \bullet denotes the specifications which apply over the full operating temperature range of $-40^{\circ}C \le T_A \le 125^{\circ}C$. V_S = 3V, 0V; V_S = 5V, 0V; V_{CM} = V_{OUT} = Half Supply unless otherwise specified. (Note 4)

				LT1638H/LT1639H			
SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V _{OS}	Input Offset Voltage	LT1638S8			200	650	μV
			•			3	mV
		LT1639S			300	750	μV
			•			3.2	mV
	Input Offset Voltage Drift (Note 9)		•			15	μV/°C
l _{os}	Input Offset Current		•			15	nA
		V _{CM} = 44V (Note 5)	•			10	μA
I _B	Input Bias Current		•			150	nA
		V _{CM} = 44V (Note 5)	•			100	μΑ
	Input Voltage Range		•	0.3		44	V
CMRR	Common Mode Rejection Ratio	$V_{CM} = 0.3V$ to $V_{CC} - 1V$	•	76			dB
		$V_{CM} = 0.3V$ to 44V		72			dB
A _{VOL}	Large-Signal Voltage Gain	$V_{S} = 3V, V_{0} = 500 \text{mV} \text{ to } 2.5V, R_{L} = 10 \text{k}$		200	1500		V/mV
				20			V/mV
		$V_{S} = 5V, V_{0} = 500mV$ to 4.5V, $R_{L} = 10k$		400	1500		V/mV
			•	35			V/mV
V _{OL}	Output Voltage Swing Low	No Load	•			15	mV
		I _{SINK} = 5mA	•			900	mV
		$V_{\rm S}$ = 5V, $I_{\rm SINK}$ = 10mA	•			1500	mV
V _{OH}	Output Voltage Swing High	$V_{\rm S} = 3V$, No Load	•	2.9			V
		$V_{\rm S} = 3V, I_{\rm SOURCE} = 5mA$	•	2			V
		$V_{\rm S} = 5V$, No Load	•	4.9			V
		$V_{\rm S}$ = 5V, I _{SOURCE} = 10mA	•	3.5			V
PSRR	Power Supply Rejection Ratio	$V_{\rm S} = 3V$ to 12.5V, $V_{\rm CM} = V_{\rm O} = 1V$	•	80			dB
	Minimum Supply Voltage			2.7			V
	Reverse Supply Voltage	I _S = -100μA		18			V
Is	Supply Current				170	230	μA
0	(Note 6)		•			450	μA
GBW	Gain Bandwidth Product	f = 5kHz		650	1075		kHz
	(Note 5)		•	350			kHz
SR	Slew Rate	$A_V = -1, R_L = \infty$		0.21	0.38		V/µs
	(Note 7)			0.1			V/µs



16389f

ELECTRICAL CHARACTERISTICS

The \bullet denotes the specifications which apply over the full operating temperature range of $-40^{\circ}C \le T_A \le 125^{\circ}C$, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = \pm 15V$, $V_{CM} = 0V$, $V_{OUT} = 0V$, $V_{SHDN} = V^-$ unless otherwise specified. (Note 4)

				LT1	638H/LT16	39H	
SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V _{OS}	Input Offset Voltage	LT1638S8			250	850	μV
			•			3.4	mV
		LT1639S			350	950	μV
			•			3.6	mV
	Input Offset Voltage Drift (Note 9)		•			15	μV/°C
los	Input Offset Current		•			25	nA
I _B	Input Bias Current		•			250	nA
CMRR	Common Mode Rejection Ratio	V _{CM} = -14.7V to 29V	•	72			dB
A _{VOL}	Large-Signal Voltage Gain	$V_0 = \pm 14V, R_L = 10k$		200	500		V/mV
			•	15			V/mV
V ₀	Output Voltage Swing	No Load	•	±14.8			V
		$I_{OUT} = \pm 5 \text{mA}$	•	±14			V
		$I_{OUT} = \pm 10 \text{mA}$	•	±13.4			V
PSRR	Power Supply Rejection Ratio	$V_{S} = \pm 1.5V$ to $\pm 22V$	•	84			dB
	Minimum Supply Voltage		•	±1.35			V
ls	Supply Current				205	280	μA
			•			550	μA
GBW	Gain Bandwidth Product	f = 5kHz		750	1200		kHz
			•	400			kHz
SR	Slew Rate	$A_V = -1, R_L = \infty, V_0 = \pm 10V,$		0.225	0.4		V/µs
		Measure at $V_0 = \pm 5V$	•	0.1			V/µs

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: A heat sink may be required to keep the junction temperature below absolute maximum. This depends on the power supply voltage and how many amplifiers are shorted.

Note 3: The LT1638C/LT1639C and LT1638I/LT1639I are guaranteed functional over the operating temperature range of -40° C to 85° C. The LT1638H/LT1639H are guaranteed functional over the operating temperature range of -40° C to 125° C.

Note 4: The LT1638C/LT1639C are guaranteed to meet specified performance from 0°C to 70°C and are designed, characterized and expected to meet specified performance from -40°C to 85°C but not tested or QA sampled at these temperatures. The LT1638I/LT1639I are guaranteed to meet specified performance from -40°C to 85°C. The LT1638H/LT1639H are guaranteed to meet specified performance from -40°C to 125°C.

Note 5: V_S = 5V limits are guaranteed by correlation to V_S = 3V and V_S = ±15V or V_S = ±22V tests.

Note 6: $V_S = 3V$ limits are guaranteed by correlation to $V_S = 5V$ and $V_S = \pm 15V$ or $V_S = \pm 22V$ tests.

Note 7: Guaranteed by correlation to slew rate at V_S = $\pm 15V$, and GBW at V_S = 3V and V_S = $\pm 15V$ tests.

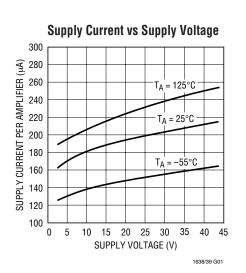
Note 8: This specification implies a typical input offset voltage of 2mV at $V_{CM} = 44V$ and a maximum input offset voltage of 5mV at $V_{CM} = 44V$. **Note 9:** This parameter is not 100% tested.

Note 10: The θ_{JA} specified for the DD package is with minimal PCB heat spreading metal. Using expanded metal area on all layers of a board reduces this value.

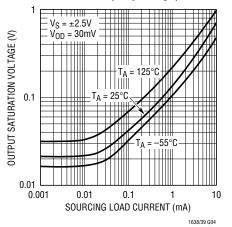


16389fd

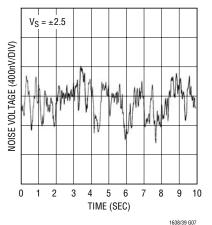
TYPICAL PERFORMANCE CHARACTERISTICS

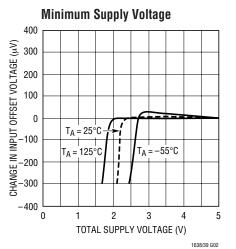


Output Saturation Voltage vs Load Current (Output High)

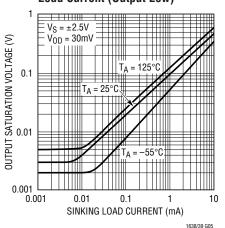


0.1Hz to 10Hz Noise Voltage





Output Saturation Voltage vs Load Current (Output Low)



Noise Voltage Density vs

10

FREQUENCY (Hz)

100

1k

1638/39 G09

Frequency

70

60

50

40

30

20

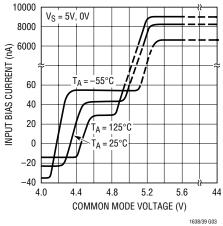
10

0

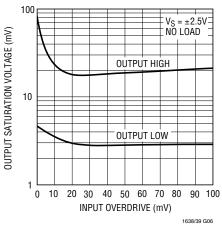
1

INPUT NOISE VOLTAGE DENSITY (nV/VHz)

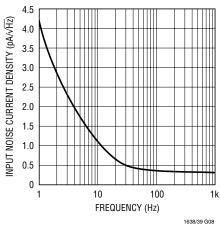
Input Bias Current vs Common Mode Voltage



Output Saturation Voltage vs Input Overdrive

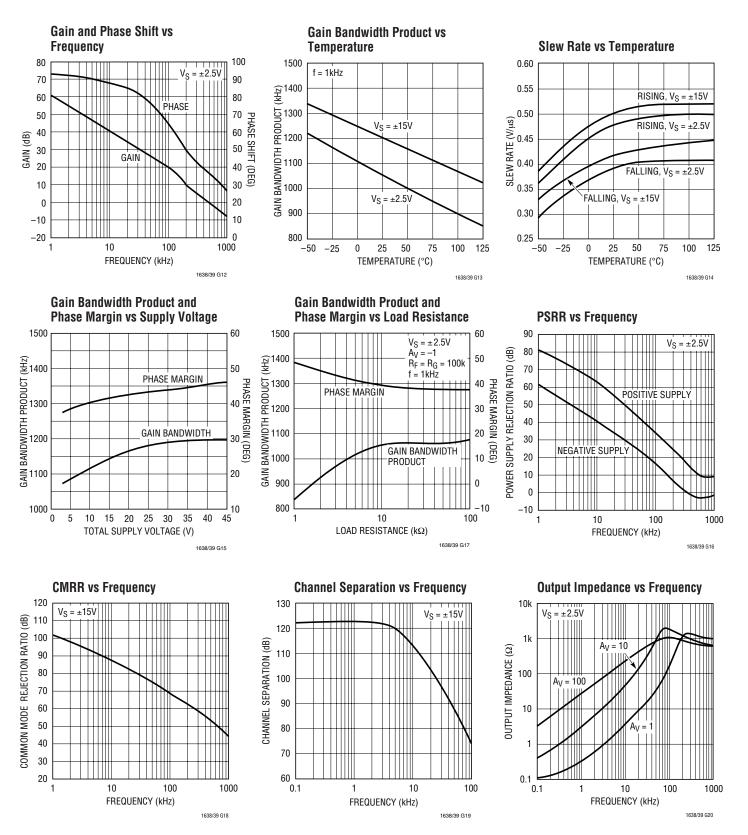


Input Noise Current Density vs Frequency



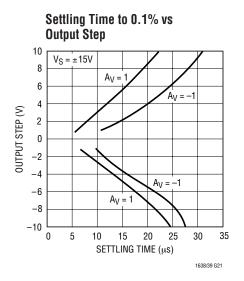


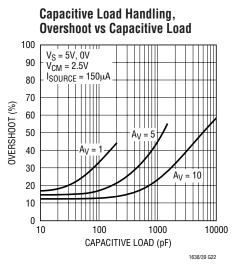
TYPICAL PERFORMANCE CHARACTERISTICS

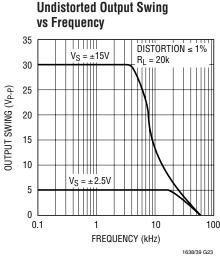




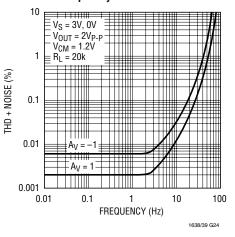
TYPICAL PERFORMANCE CHARACTERISTICS



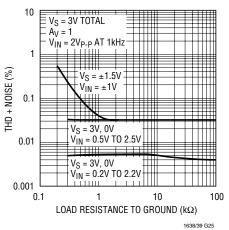




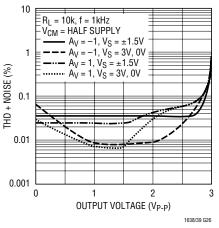
Total Harmonic Distortion + Noise vs Frequency



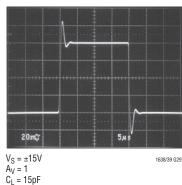
Total Harmonic Distortion + Noise vs Load Resistance

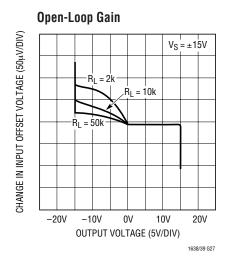


Total Harmonic Distortion + Noise vs Output Voltage

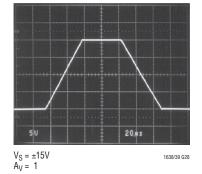


Small-Signal Response











APPLICATIONS INFORMATION

Supply Voltage

The positive supply pin of the LT1638/LT1639 should be bypassed with a small capacitor (typically 0.1μ F) within an inch of the pin. When driving heavy loads an additional 4.7μ F electrolytic capacitor should be used. When using split supplies, the same is true for the negative supply pin.

The LT1638/LT1639 are protected against reverse battery voltages up to 18V. In the event a reverse battery condition occurs, the supply current is less than 1nA.

The LT1638/LT1639 can be shut down by removing V⁺. In this condition the input bias current is less than 0.1nA, even if the inputs are 44V above the negative supply.

At temperatures greater than 70°C, when operating the LT1638/LT1639 on total supplies of 10V or more, the supply must not be brought up faster than $1V/\mu s$. Increasing the bypass capacitor and/or adding a small resistor in series with the supply will limit the rise time.

Inputs

The LT1638/LT1639 have two input stages, NPN and PNP (see the Simplified Schematic), resulting in three distinct operating regions as shown in the Input Bias Current vs Common Mode typical performance curve.

For input voltages about 0.8V or more below V⁺, the PNP input stage is active and the input bias current is typically -20nA. When the input common mode voltage is within 0.5V of the positive rail, the NPN stage is operating and the input bias current is typically 40nA. Increases in temperature will cause the voltage at which operation switches from the PNP input stage to the NPN input stage to move towards V⁺. The input offset voltage of the NPN stage is untrimmed and is typically 600μ V.

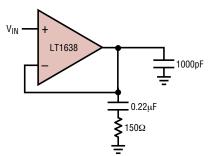
A Schottky diode in the collector of each NPN transistor allow the LT1638/LT1639 to operate over the top, with either or both of its inputs above V⁺. At about 0.3V above V⁺ the NPN input transistor is fully saturated and the input bias current is typically 8μ A at room temperature. The input offset voltage is typically 2mV when operating above V⁺. The LT1638/LT1639 will operate with its inputs 44V above V⁻ regardless of V⁺. The inputs are protected against excursions of 2V below V^- by an internal 1k resistor in series with each input and a diode from the input to the negative supply. If the inputs can go more than 2V below V^- , an additional external resistor is required. A 10k resistor will protect the input against excursions as much as 10V below V^- . The input stage of the LT1638/LT1639 incorporates phase reversal protection to prevent the output from phase reversing for inputs below V^- . There are no clamping diodes between the inputs and the maximum differential input voltage is 44V.

Output

The output of the LT1638/LT1639 can swing within 20mV of the positive rail with no load, and within 3mV of the negative rail with no load. When monitoring voltages within 20mV of the positive rail or within 3mV of the negative rail, gain should be taken to keep the output from clipping. The LT1638/LT1639 are capable of sinking and sourcing over 40mA on \pm 15V supplies; sourcing current capability is reduced to 20mA at 5V total supplies as noted in the electrical characteristics.

The LT1638/LT1639 are internally compensated to drive at least 200pF of capacitance under any output loading conditions. A 0.22μ F capacitor in series with a 150Ω resistor between the output and ground will compensate these amplifiers for larger capacitive loads, up to 1000pF, at all output currents.

Optional Output Compensation for Capacitive Loads Greater than 200pF



Distortion

There are two main contributors of distortion in op amps: output crossover distortion as the output transitions from sourcing to sinking current and distortion caused by 16389fc



APPLICATIONS INFORMATION

nonlinear common mode rejection. If the op amp is operating inverting there is no common mode induced distortion. If the op amp is operating in the PNP input stage (input is not within 0.8V of V⁺), the CMRR is very good, typically 98dB. When the LT1638 switches between input stages there is significant nonlinearity in the CMRR. Lower load resistance increases the output crossover distortion, but has no effect on the input stage transition distortion. For lowest distortion the LT1638/LT1639 should be operated single supply, with the output always sourcing

TYPICAL APPLICATIONS

With 1.2MHz bandwidth, Over-The-Top capability, reverse-battery protection and rail-to-rail input and output features, the LT1638/LT1639 are ideal candidates for general purpose applications.

The lowpass slope limiting filter in Figure 1 limits the maximum dV/dT (not frequency) that it passes. When the input signal differs from the output by one forward diode drop, D1 or D2 will turn on. With a diode on, the voltage across R2 will be constant and a fixed current, $V_{DIODE}/R2$, will flow through capacitor C1, charging it linearly instead of exponentially. The maximum slope that the circuit will pass is equal to V_{DIODE} divided by (R2)(C1). No matter how fast the input changes the output will never change any faster than the dV/dT set by the diodes and (R2)(C).

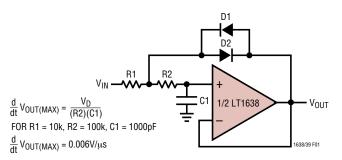


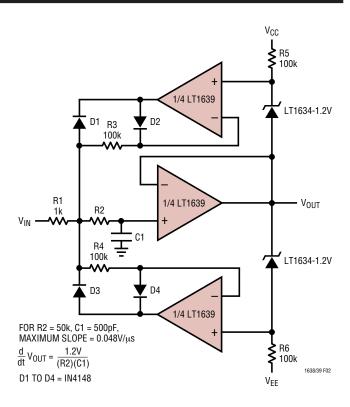
Figure 1. Lowpass Slope Limiting Filter

A modification of this application is shown in Figure 2 using references instead of diodes to set the maximum slope. By using references, the slope is independent of temperature. A scope photo shows a $1V_{P-P}$, 2kHz input signal with a 2V pulse added to the sine wave; the circuit passes the 2kHz signal but limits the slope of the pulse.

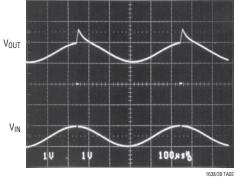
current and with the input voltage swing between ground and (V⁺ - 0.8V). See the Typical Performance Characteristics curves.

Gain

The open-loop gain is almost independent of load when the output is sourcing current. This optimizes performance in single supply applications where the load is returned to ground. The typical performance curve of Open-Loop Gain for various loads shows the details.









TYPICAL APPLICATIONS

The application in Figure 3 utilizes the Over-The-Top capabilities of the LT1638. The 0.2Ω resistor senses the load current while the op amp and NPN transistor form a closed loop making the collector current of Q1 proportional to the load current. As a convenient monitor, the 2k load resistor converts the current into a voltage. The positive supply rail, V⁺, is not limited to the 5V supply of the op amp and could be as high as 44V.

5V Q1

The Figure 4 application uses the LT1638 in conjunction with the LT1634 micropower shunt reference. The supply current of the op amp also biases the reference. The drop across resistor R1 is fixed at 1.2V generating an output current equal to 1.2V/R1.

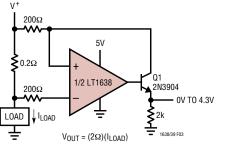


Figure 3. Positive Supply Rail Current Sense

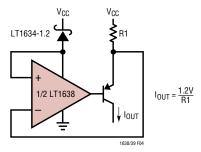
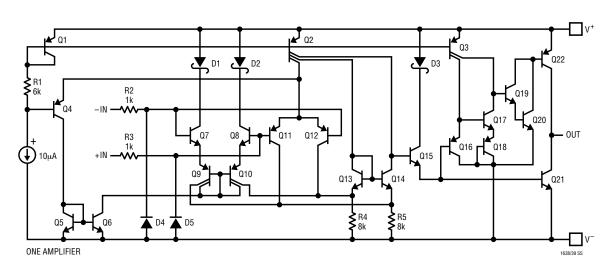


Figure 4. Current Source

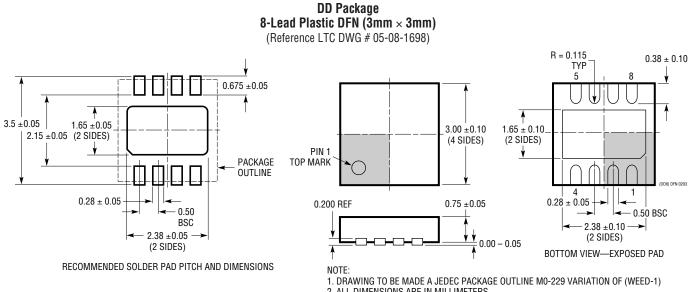


SIMPLIFIED SCHEMATIC



16389fd

PACKAGE DESCRIPTION



ALL DIMENSIONS ARE IN MILLIMETERS 2

DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE

3. MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE 4. EXPOSED PAD SHALL BE SOLDER PLATED

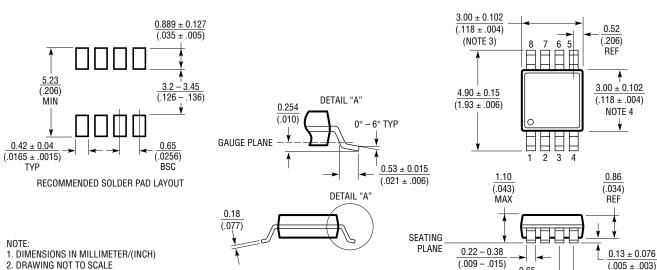
0.65

(.0256)

BSC

TYP

MS8 Package 8-Lead Plastic MSOP (Reference LTC DWG # 05-08-1660)



2. DRAWING NOT TO SCALE

3. DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.152mm (.006") PER SIDE

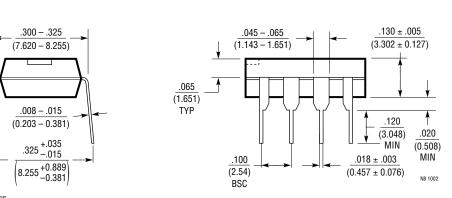
4. DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.

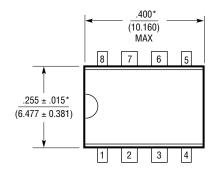
INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.152mm (.006") PER SIDE 5. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.102mm (.004") MAX

16389fc

MSOP (MS8) 0802

PACKAGE DESCRIPTION



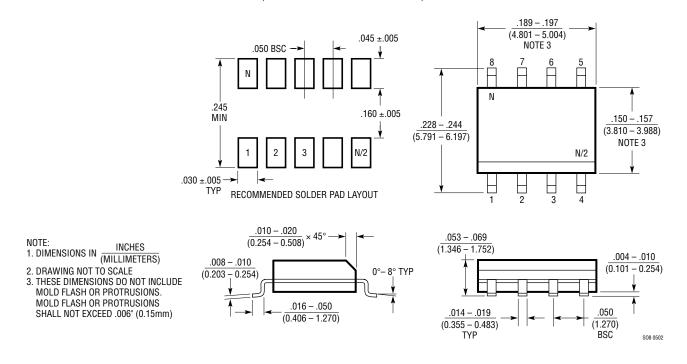


NOTE: 1. DIMENSIONS ARE <u>INCHES</u> *THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.

MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .010 INCH (0.254mm)

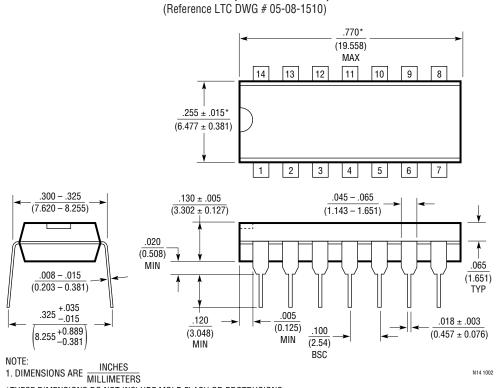


N8 Package 8-Lead PDIP (Narrow .300 Inch) (Reference LTC DWG # 05-08-1510)





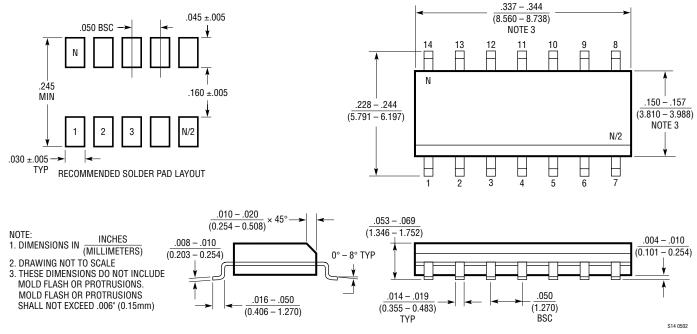
PACKAGE DESCRIPTION



N Package 14-Lead PDIP (Narrow .300 Inch)

*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .010 INCH (0.254mm)

S Package 14-Lead Plastic Small Outline (Narrow .150 Inch) (Reference LTC DWG # 05-08-1610)



16389fc



Information furnished by Linear Technology Corporation is believed to be accurate and reliable. However, no responsibility is assumed for its use. Linear Technology Corporation makes no representation that the interconnection of its circuits as described herein will not infringe on existing patent rights.

TYPICAL APPLICATION

The battery monitor in Figure 5 also demonstrates the LT1638's ability to operate with its inputs above the positive rail. In this application, a conventional amplifier would be limited to a battery voltage between 5V and ground, but the LT1638 can handle battery voltages as high as 44V. When the battery is charging, Amp B senses the voltage drop across R_S . The output of Amp B causes Q2 to drain sufficient current through R_B to balance the input of Amp B. Likewise, Amp A and Q1 form a closed

loop when the battery is discharging. The current through Q1 or Q2 is proportional to the current in R_S and this current flows into R_G and is converted into a voltage. Amp D buffers and amplifies the voltage across R_G . Amp C compares the output of Amp A and Amp B to determine the polarity of current through R_S . The scale factor for V_{OUT} with S1 open is 1V/A. With S1 closed the scale factor is 1V/100mA and currents as low as 500 μA can be measured.

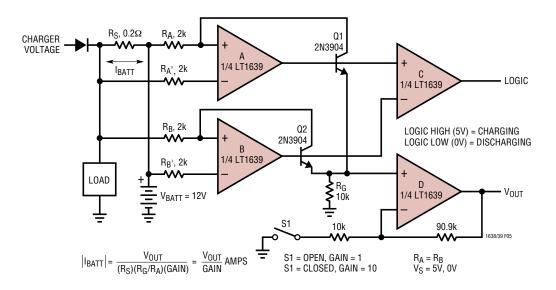


Figure 5. Battery Monitor

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1078/LT1079 LT2078/LT2079	Dual/Quad 55µA Max, Single Supply, Precision Op Amps	Input/Output Common Mode Includes Ground, 70 μ V V _{OS(MAX)} and 2.5 μ V/°C Drift (Max), 200kHz GBW, 0.07V/ μ s Slew Rate
LT1178/LT1179 LT2178/LT2179	Dual/Quad 17µA Max, Single Supply, Precison Op Amps	Input/Output Common Mode Includes Ground, 70µV $V_{OS(MAX)}$ and 4µV/°C Drift (Max), 85kHz GBW, 0.04V/µs Slew Rate
LT1366/LT1367	Dual/Quad Precision, Rail-to-Rail Input and Output Op Amps	475μV V _{OS(MAX)} , 500V/mV A _{VOL(MIN)} , 400kHz GBW
LT1490/LT1491	Dual/Quad Over-The-Top Micropower, Rail-to-Rail Input and Output Op Amps	Single Supply Input Range: –0.4V to 44V, Micropower 50µA per Amplifier, Rail-to-Rail Input and Output, 200kHz GBW
LT1636	Single Over-The-Top Micropower Rail-to-Rail Input and Output Op Amp	55 μ A Supply Current, V _{CM} Extends 44V above V _{EE} , Independent of V _{CC} ; MSOP Package, Shutdown Function

